MN1380 Series CMOS LSIs for Voltage Detection

Overview

The MN1380 series are elements that monitor the power supply voltage supplied to microcomputers and other LSI systems and issue reset signals for initializing the system after the power is first applied or for preventing runaway operation when the supply voltage fluctuates.

There is a choice of three output types: CMOS output, N-channel open drain output, and inverted CMOS output. There are also three package types: M, TO-92, and a mini type for surface mounting.

Choose the ideal element for your application from the series' wide selection of detection ranks (17 ranks between 2.0 and 4.9 volts), output types, and package types.

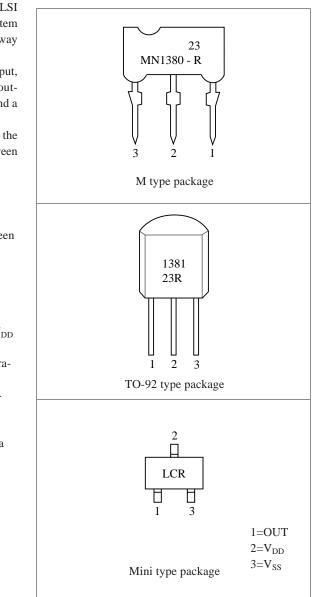
Features

- Three-pin element requiring no adjustment
- Wide selection of detection ranks (17 ranks between 2.0 and 4.9 volts)
- Highly precise detection voltage
- Detection voltage with hysteresis characteristic $\Delta VD = 50 \text{ mV}$ for ranks C to K $\Delta VD = 100 \text{ mV}$ for ranks L to U
- Low current consumption: $I_{DD} = 1\mu A$ (typ.) for $V_{DD} = 5 V$
- Low fluctuation in detection voltage with temperature (typ. 1 mV/°C)
- Wide selection of output types: CMOS output, Nchannel open drain output, and inverted CMOS output
- Wide selection of package types: M, TO-92, and a mini type for surface mounting.

Applications

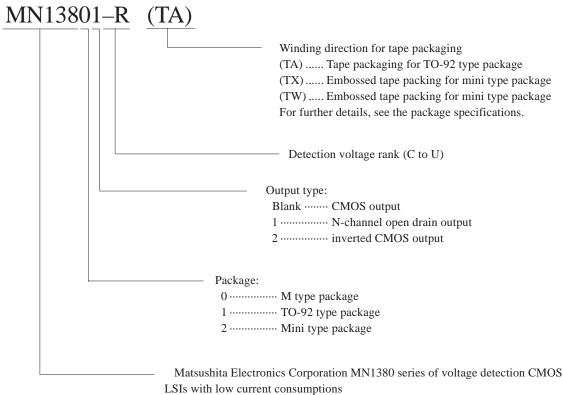
- Battery checkers
- Power outage detectors
- Level discriminators
- Memory backup systems
- Microcomputer reset circuits
- Reset circuits for other electronic circuits

Pin Assignment

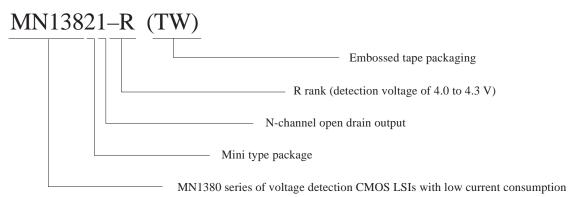


MN1380 Series Naming Conventions

The MN1380 series offers a wide selection of detection ranks, output types, package types, and packaging. All combinations use the following naming conventions. When ordering, be sure to give the correct part number using these naming conventions.



(Example)



Minimum Packaging Unit

 Bulk (M and TO-92 types)
 1,000

 Magazine (Mini type)
 50

 Taping (Mini and TO-92 types)
 3,000

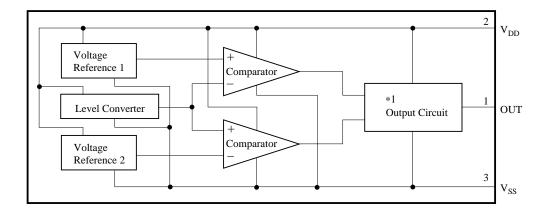
Series Lineup

Output Package	M type Package	TO-92 type Package	Mini type Package
CMOS output	MN1380	MN1381	MN1382
N-channel open drain output	MN13801	MN13811	MN13821
Inverted CMOS output	MN13802	MN13812	MN13822

Detection Ranks (on Voltage)

Rank	Detection Voltage for Drop in	Power Supply Voltage (V _{DL})	Unit		Hysteresis Width (∆VD)	Unit
	min	max	Onic	min	max	Onic
С	2.0	2.2				
D	2.1	2.3				
Е	2.2	2.4	v	50	300	mV
F	2.3	2.5	v	50	300	111 V
G	2.4	2.6				
Н	2.5	2.7				
J	2.6	2.9	V	50	200	mV
K	2.8	3.1	v	50	300	mV
L	3.0	3.3				
М	3.2	3.5				
Ν	3.4	3.7				
Р	3.6	3.9				
Q	3.8	4.1	V	100	300	mV
R	4.0	4.3				
S	4.2	4.5				
Т	4.4	4.7				
U	4.6	4.9				

Block Diagram



Note *1: Circuits vary slightly depending on the output type (CMOS output, N-channel open drain output, or inverted CMOS output)

Pin Descriptions

Pin No.	Symbol	Function Description
1	OUT	Reset signal output pin
2	V _{DD}	Power supply pin
3	V _{SS}	Ground pin

■ Absolute Maximum Ratings V_{SS}=0V, Ta=25°C

Parameter	Symbol	Rating	Unit
Power supply voltage	V _{DD}	7.0	V
Output voltage	Vo	-0.3 to V _{DD} +0.3	V
Operating ambient temperature	Та	-20 to +70	°C
Storage temperature	T _{stg}	-55 to +125	°C

■ Recommended Operating Conditions V_{SS}=0V, Ta=25°C

Parameter	Symbol	Conditions	min	typ	max	Unit
Power supply voltage	V _{DD}	See Figures 1 and 4.	1.5		6.0	V

Electrical Characteristics

1) DC Characteristics $V_{SS}=0V$, Ta=-20°C to +70°C

Parameter	Symbol	Con	ditions	min	typ	max	Unit
Power supply current	I _{DD}	$V_{DD} = 5 V^{*1}$ Load resistance	ce = 10 kW		1	5	μA
Detection voltage for drop in power supply voltage *2	V _{DL}	Ta=25°C		*2		*2	V
Detection voltage hysteresis width *2	ΔVD	See Figures 1	and 4.	*2		*2	mV
"H" level output voltage	V _{OH}	CMOS output	I _{OH} =-40µA	0.8V _{DD}		V _{DD}	
		Inverted CMOS output	V _{DD} =1.8V I _{OH} =-0.5mA	0.8		V _{DD} -1.5	V
"L" level output voltage	V _{OL}	N-channel open drain output	V _{DD} =1.8V I _{OL} =0.7mA	V _{SS}		0.4	V
		Inverted CMOS output	V _{DD} =6.0V I _{OH} =0.3mA	V _{SS}		0.6	V

Notes

*1: This includes the output pin's leakage current.

*2: For particulars, see the detection voltage rank table.

Electrical Characteristics (continued)

2) AC Characteristics $V_{SS}=0V$, Ta=25°C

Parameter	Symbol	Cond	itions	All	owable Value (t	yp)	Unit
Falametel	Symbol	Cond		MN1380 MN1381	MN13801 MN13811	MN13802 MN13812	Unit
			Rank	MN1382	MN13821	MN13822	
			С				
			D				
			Е	3.0	2.5	230.0	
			F				
			G				
		See	Н				
Reset release time	t _{OH}	Figures	J	3.0	3.0	100.0	μs
		2 and 3.	K				
			L				
			М				
			Ν				
			Р				
			Q	2.0	4.0	30.0	
			R				
			S				
			Т				
			С				
			D				
			Е	250.0	160.0	3.0	
			F				
			G				
		See	Н				
Reset time	t _{OL}	Figures	J	115.0	100.0	3.0	μs
	012	2 and 3.	К				
			L				-
			М				
			Ν				
			Р				
			Q	15.0	35.0	3.0	
			R				
			S				
			T				

Description of Operation

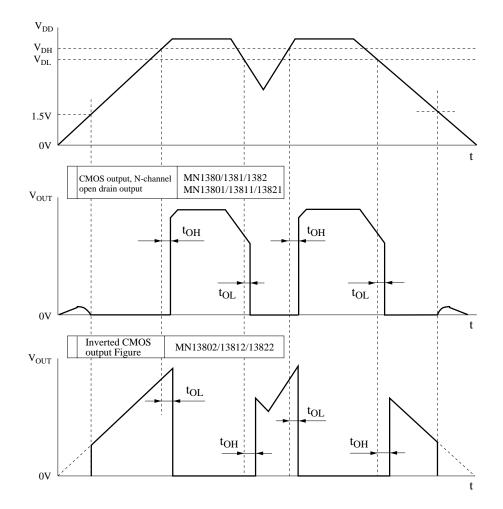


Figure 1. Description of Operation

Notes

- 1: Output cannot be specified for power supply voltages under 1.5 V because operation is not guaranteed for that range.
- 2: V_{DL}: Detection voltage for drop in power supply voltage

 $V_{\text{DH}}\!\!:$ Detection voltage for rise in power supply voltage

- t_{OL} : Time lag between the time that the power supply voltage reaches the detection voltage (V_{DL} or V_{DH}) and the time that the output pin (OUT) goes to "L" level.
- t_{OH} : Time lag between the time that the power supply voltage reaches the detection voltage (V_{DL} or V_{DH}) and the time that the output pin (OUT) goes to "H" level.
- 3: These characteristics for the N-channel open drain output are when a load resistor is connected between the OUT and V_{DD} pins.

Description for Measuring the Output Characteristics

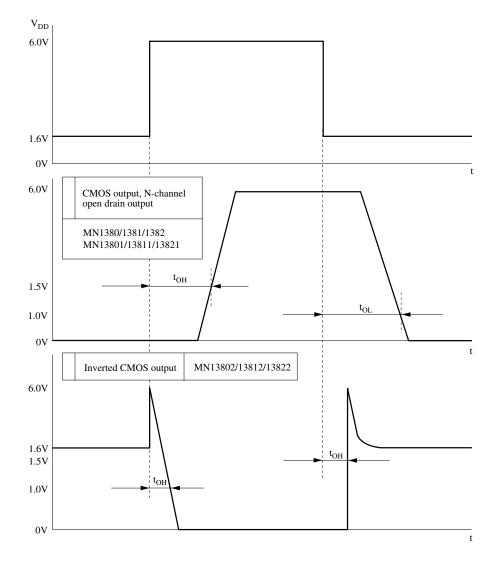
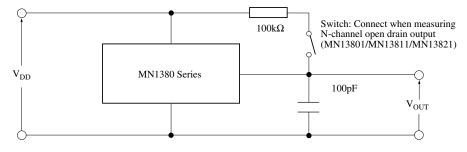


Figure 2. Description chart of Measuring the Output Characteristics





Description for Measuring the I/O Characteristics

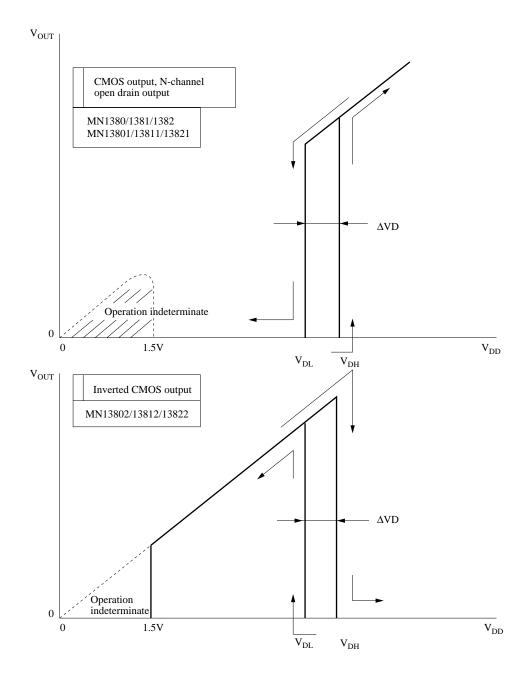


Figure 4. Description chart for Measuring the I/O Characteristics

Notes

1: Output cannot be specified for power supply voltages under 1.5 V because operation is not guaranteed for that range.

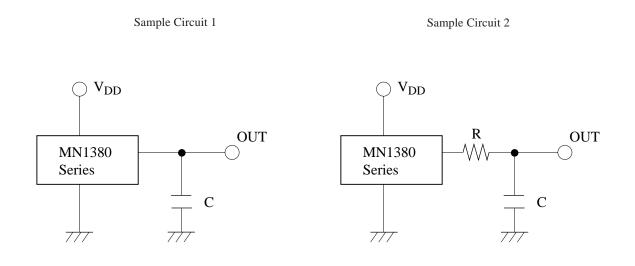
2: V_{DL} : Detection voltage for drop in power supply voltage

V_{DH}: Detection voltage for rise in power supply voltage

3: These characteristics for the N-channel open drain output are when a load resistor is connected between the OUT and V_{DD} pins.

Application Circuit Example

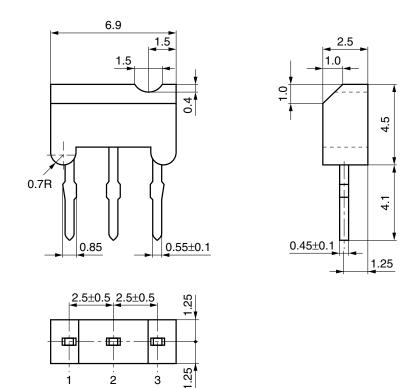
Connect resistors, capacitors, and the like only to the output pin on the MN1380 series element. Note that connecting them to the Power source pins changes V_{DH} , V_{DL} , and ΔVD .



Select the values of R and C to match the application.

Package Dimensions (Unit: mm)

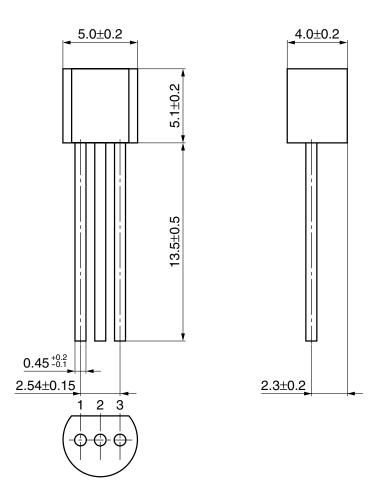
M type package



Note) The package will be changed to lead-free type (M3A). See the new package dimensions section later of this datasheet.

Package Dimensions (Unit: mm)(continued)

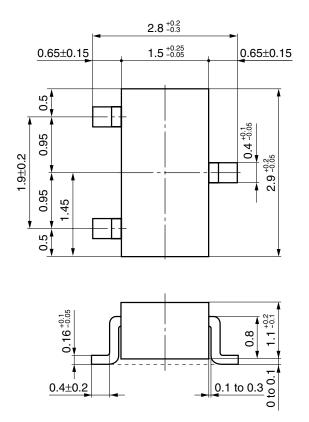
TO-92 type package



Note) The package will be changed to lead-free type (SSIP003-P-0000S). See the new package dimensions section later of this datasheet.

Package Dimensions (Unit: mm)(continued)

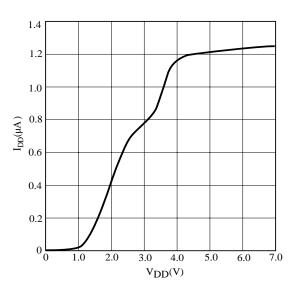
Mini type package



Note) The package will be changed to lead-free type (MINI-3DC). See the new package dimensions section later of this datasheet.

Reference Characteristics

The following characteristics curves represent results from a specific sample therefore they do not guarantee the characteristics for the final product.



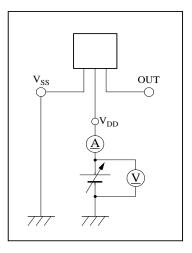
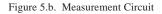
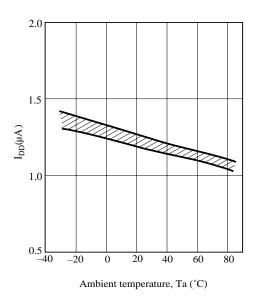


Figure 5.a. I_{DD} vs. V_{DD} Characteristic (Rank Q)







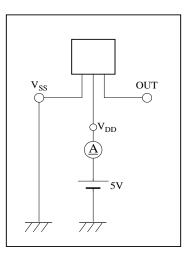
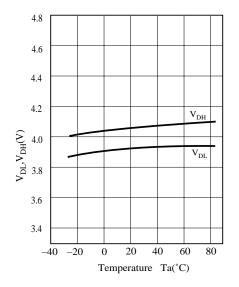


Figure 6.b. Measurement Circuit



Reference Characteristics (continued)

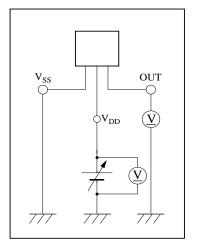
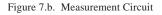
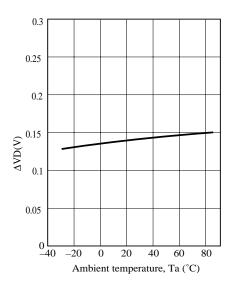


Figure 7.a. V_{DL}/V_{DH} Temperature Characteristic (Rank Q)

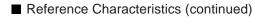




V_{SS} OUT V_{DD} V V_{DD} V

Figure 8.a. ΔVD Temperature Characteristic (Rank Q)

Figure 8.b. Measurement Circuit



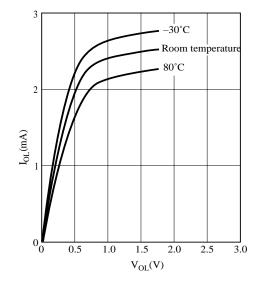


Figure 9.a. $\,I_{OL}\,vs.\,V_{OL}\,Characteristic$

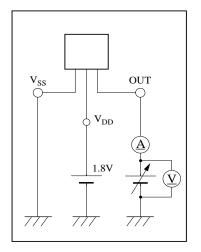
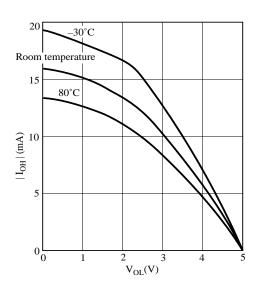


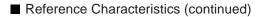
Figure 9.b. Measurement Circuit



V_{SS} OUT V_{DD} V_{DD} V_{DD} V_{DD}

Figure 10.a. $I_{OH}\,vs.\;V_{OH}$ Characteristic

Figure 10.b. Measurement Circuit



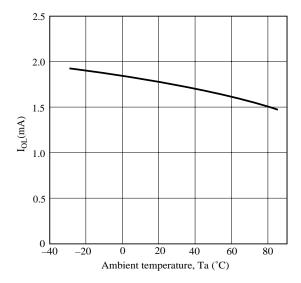


Figure 11.a. I_{OL} vs. Temperature Characteristic

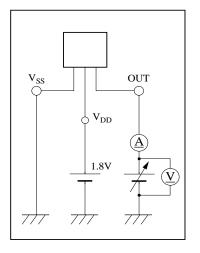
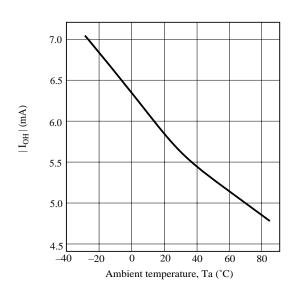


Figure 11.b. Measurement Circuit



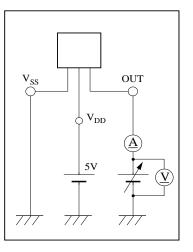




Figure 12.b. Measurement Circuit

■ TO-92 Type Package Taping-Specifications (MN1381/MN13811/MN13812)

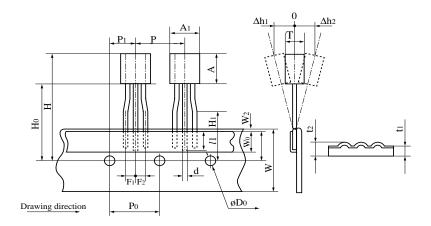


Figure 13. TO-92 Type Package Taping-Dimensions (Ammunition pack)

Name	Symbol	Length (mm)
Product height*	А	5.3 max
Product width*	A1	5.2 max
Product thickness*	Т	4.2 max
Lead width*	d	$0.45^{+0.15}_{-0.1}$
Taped lead length	<i>l</i> 1	2.0 max
Product pitch	Р	12.7±1.0
Feed hole pitch	P0	12.7±0.3
Feed hole position	P1	6.35±0.5
Lead spacing	F1, F2	$2.5^{+0.5}_{-0.2}$
Product deflection angle	$\Delta h1, \Delta h2$	2.0 max
Tape width	W	$18.0^{+1.0}_{-0.5}$

TO-92 Type Package Taping Dimensions (Ammunition pack)

Name	Symbol	Length (mm)
Adhesive tape width	W0	6.0±0.5
Feed hole position	W1	9.0±0.5
Adhesive tape position	W2	0.5 max
Distance to top of product	Н	25.0 max
Distance to bottom of product	H0	19.0±0.5
Lead clinch height	H1	16.0±0.5
Feed hole diameter	D0	4.0±0.2
Tape thickness	t1	0.7±0.2
Total tape thickness	t2	1.5 max
Total tape thickness	t2	1.5 max

Note*1: For further details, see the specifications issued separately.

VV	Н	D
330	250	41

Unit: mm

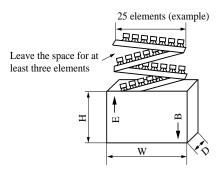
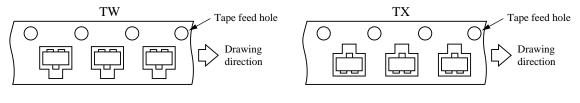


Figure 14. Box Dimensions for TO-92 Type Packages with Ammunition pack

Embossed Taping Specifications for Mini Type Package (MN1382/MN13821/MN13822)

There is a choice of two orientations, TW and TX, for the product relative to the tape.



(Marking surface on top)

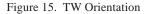
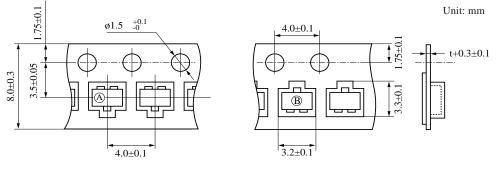


Figure 16. TX Orientation

(Marking surface on top)



Product orientation A is labeled TW; orientation B, TX.

Figure 17. Embossed Taping Dimensions for Mini Type Package

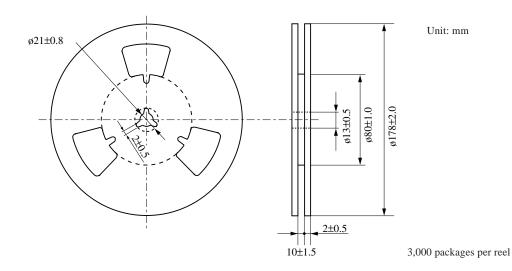


Figure 18. Embossed Taping Reel Dimensions for Mini Type Package

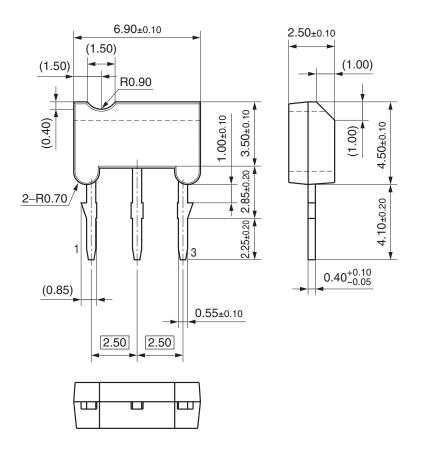
Reliability Testing Results for MN1380 Series

(1) M type package (MN1380/MN13801/MN13802) and TO-92 type package (MN1381/MN13811/MN13812)

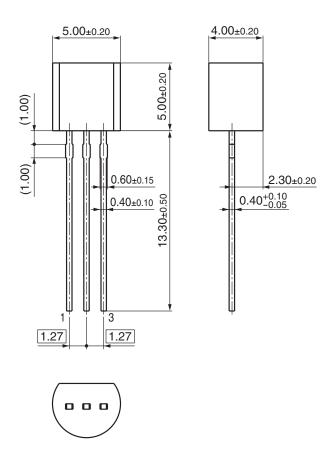
Test Subjects	Test Conditions	Results
Operating lifetime test	V _{DD} =5.5V, Ta=125°C, t=1000hrs	0/15
High-temperature storage test	Ta=150°C, t=1000hrs	0/15
Low-temperature storage test	Ta=-65°C, t=1000hrs	0/15
High-temperature,	Ta=85°C, RH=85%, t=1000hrs	0/15
high-humidity storage test		
High-temperature,	V _{DD} =5.5V, Ta=85°C, RH=85%, t=1000hrs	0/15
high-humidity bias test		
Thermal shock test	Ta=150°C and -65°C.	0/15
	Five minutes at each temperature for ten cycles	
Temperature cycle test	Ta=150°C and -65°C.	0/15
	Thirty minutes at each temperature for ten cycles	
Pressure cooker test	Two atmospheres for 50 hours at ambient temperature (Ta) of 121°C	0/15
Soldering test	Ambient temperature (Ta) of 230°C for five seconds	0/15
Solder heat resistance test	Ambient temperature (Ta) of 270°C for ten seconds	0/15
2) Mini type package (MN1382/M	AN13821/MN13822)	
2) Mini type package (MN1382/M Test Subjects	AN13821/MN13822) Test Conditions	Results
	· · · · · · · · · · · · · · · · · · ·	Results 0/15
Test Subjects	Test Conditions	
Test Subjects Operating lifetime test	Test Conditions V _{DD} =5.5V, Ta=125°C, t=1000hrs	0/15
Test Subjects Operating lifetime test High-temperature storage test	Test Conditions V_{DD} =5.5V, Ta=125°C, t=1000hrsTa=150°C, t=1000hrs	0/15 0/15
Test SubjectsOperating lifetime testHigh-temperature storage testLow-temperature storage test	Test Conditions V_{DD} =5.5V, Ta=125°C, t=1000hrs Ta=150°C, t=1000hrs Ta=-65°C, t=1000hrs	0/15 0/15 0/15
Test SubjectsOperating lifetime testHigh-temperature storage testLow-temperature storage testHigh-temperature,	Test Conditions V_{DD} =5.5V, Ta=125°C, t=1000hrs Ta=150°C, t=1000hrs Ta=-65°C, t=1000hrs	0/15 0/15 0/15
Test SubjectsOperating lifetime testHigh-temperature storage testLow-temperature storage testHigh-temperature,high-humidity storage test	Test Conditions V _{DD} =5.5V, Ta=125°C, t=1000hrs Ta=150°C, t=1000hrs Ta=-65°C, t=1000hrs Ta=85°C, RH=85%, t=1000hrs	0/15 0/15 0/15 0/15
Test SubjectsOperating lifetime testHigh-temperature storage testLow-temperature storage testHigh-temperature,high-humidity storage testHigh-temperature,	Test Conditions V _{DD} =5.5V, Ta=125°C, t=1000hrs Ta=150°C, t=1000hrs Ta=-65°C, t=1000hrs Ta=85°C, RH=85%, t=1000hrs	0/15 0/15 0/15 0/15
Test SubjectsOperating lifetime testHigh-temperature storage testLow-temperature storage testHigh-temperature,high-humidity storage testHigh-temperature,high-temperature,high-temperature,high-temperature,high-temperature,	Test Conditions V _{DD} =5.5V, Ta=125°C, t=1000hrs Ta=150°C, t=1000hrs Ta=-65°C, t=1000hrs Ta=85°C, RH=85%, t=1000hrs V _{DD} =5.5V, Ta=85°C, RH=85%, t=1000hrs	0/15 0/15 0/15 0/15 0/15
Test SubjectsOperating lifetime testHigh-temperature storage testLow-temperature storage testHigh-temperature,high-humidity storage testHigh-temperature,high-temperature,high-temperature,high-temperature,high-temperature,	Test Conditions V _{DD} =5.5V, Ta=125°C, t=1000hrs Ta=150°C, t=1000hrs Ta=-65°C, t=1000hrs Ta=85°C, RH=85%, t=1000hrs V _{DD} =5.5V, Ta=85°C, RH=85%, t=1000hrs Ta=150°C and -65°C.	0/15 0/15 0/15 0/15 0/15
Test SubjectsOperating lifetime testHigh-temperature storage testLow-temperature storage testHigh-temperature,high-humidity storage testHigh-temperature,high-humidity bias testThermal shock test	Test Conditions V_{DD} =5.5V, Ta=125°C, t=1000hrs Ta=150°C, t=1000hrs Ta=-65°C, t=1000hrs Ta=85°C, RH=85%, t=1000hrs V_{DD} =5.5V, Ta=85°C, RH=85%, t=1000hrs Ta=150°C and -65°C. Five minutes at each temperature for ten cycles	0/15 0/15 0/15 0/15 0/15 0/15
Test SubjectsOperating lifetime testHigh-temperature storage testLow-temperature storage testHigh-temperature,high-humidity storage testHigh-temperature,h	Test Conditions V_{DD} =5.5V, Ta=125°C, t=1000hrs Ta=150°C, t=1000hrs Ta=-65°C, t=1000hrs Ta=85°C, RH=85%, t=1000hrs V_{DD} =5.5V, Ta=85°C, RH=85%, t=1000hrs Ta=150°C and -65°C. Five minutes at each temperature for ten cycles Ta=150°C and -65°C. Ta=150°C and -65°C.	0/15 0/15 0/15 0/15 0/15 0/15
Operating lifetime testHigh-temperature storage testLow-temperature storage testHigh-temperature,high-humidity storage testHigh-temperature,high-humidity bias testThermal shock testTemperature cycle test	Test Conditions V_{DD} =5.5V, Ta=125°C, t=1000hrsTa=150°C, t=1000hrsTa=-65°C, t=1000hrsTa=85°C, RH=85%, t=1000hrs V_{DD} =5.5V, Ta=85°C, RH=85%, t=1000hrsTa=150°C and -65°C.Five minutes at each temperature for ten cyclesTa=150°C and -65°C.Thirty minutes at each temperature for ten cycles	0/15 0/15 0/15 0/15 0/15 0/15 0/15

Note*1: Note that the testing conditions for the mini package differ from those for the other two packages.

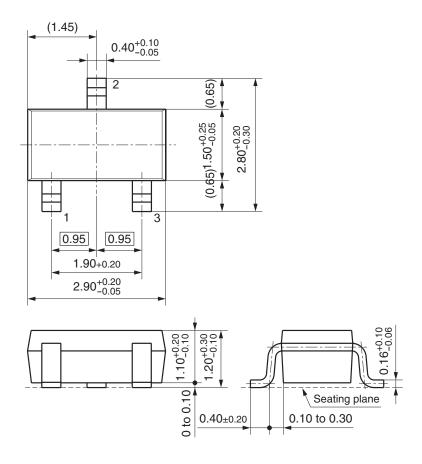
- New Package Dimensions (Unit: mm)
- M3A (Lead-free package)



- New Package Dimensions (Unit: mm)(continued)
- SSIP003-P-0000S (Lead-free package)



- New Package Dimensions (Unit: mm)(continued)
- MINI-3DC (Lead-free package)



Request for your special attention and precautions in using the technical information and semiconductors described in this material

- (1) An export permit needs to be obtained from the competent authorities of the Japanese Government if any of the products or technologies described in this material and controlled under the "Foreign Exchange and Foreign Trade Law" is to be exported or taken out of Japan.
- (2) The technical information described in this material is limited to showing representative characteristics and applied circuit examples of the products. It does not constitute the warranting of industrial property, the granting of relative rights, or the granting of any license.
- (3) The products described in this material are intended to be used for standard applications or general electronic equipment (such as office equipment, communications equipment, measuring instruments and household appliances).

Consult our sales staff in advance for information on the following applications:

- Special applications (such as for airplanes, aerospace, automobiles, traffic control equipment, combustion equipment, life support systems and safety devices) in which exceptional quality and reliability are required, or if the failure or malfunction of the products may directly jeopardize life or harm the human body.
- Any applications other than the standard applications intended.
- (4) The products and product specifications described in this material are subject to change without notice for reasons of modification and/or improvement. At the final stage of your design, purchasing, or use of the products, therefore, ask for the most up-to-date Product Standards in advance to make sure that the latest specifications satisfy your requirements.
- (5) When designing your equipment, comply with the guaranteed values, in particular those of maximum rating, the range of operating power supply voltage and heat radiation characteristics. Otherwise, we will not be liable for any defect which may arise later in your equipment. Even when the products are used within the guaranteed values, redundant design is recommended, so that such equipment may not violate relevant laws or regulations because of the function of our products.
- (6) When using products for which dry packing is required, observe the conditions (including shelf life and after-unpacking standby time) agreed upon when specification sheets are individually exchanged.
- (7) No part of this material may be reprinted or reproduced by any means without written permission from our company.

Please read the following notes before using the datasheets

- A. These materials are intended as a reference to assist customers with the selection of Panasonic semiconductor products best suited to their applications.
 Due to modification or other reasons, any information contained in this material, such as available product types, technical data, and so on, is subject to change without notice.
 Customers are advised to contact our semiconductor sales office and obtain the latest information before starting precise technical research and/or purchasing activities.
- B. Panasonic is endeavoring to continually improve the quality and reliability of these materials but there is always the possibility that further rectifications will be required in the future. Therefore, Panasonic will not assume any liability for any damages arising from any errors etc. that may appear in this material.
- C. These materials are solely intended for a customer's individual use. Therefore, without the prior written approval of Panasonic, any other use such as reproducing, selling, or distributing this material to a third party, via the Internet or in any other way, is prohibited.